Vishay Semiconductors



Schottky Rectifier, 3.5 A



Bas	е
catho	de
Å	4, 2
D 1	03
node	Anode

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	3.5 A				
V _R	100 V				
V _F at I _F	See Electrical table				
I _{RM}	4.9 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	5 mJ				

FEATURES

- Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-30WQ10FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	3.5	A			
V _{RRM}		100	V			
I _{FSM}	$t_p = 5 \ \mu s \ sine$	440	A			
V _F	3 A _{pk} , T _J = 125 °C	0.63	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-30WQ10FNHM3	UNITS		
Maximum DC reverse voltage	V _R	100	V		
Maximum working peak reverse voltage	V _{RWM}	100	v		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C	, rectangular waveform	3.5		
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	440	А	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	70		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 10 mH		5.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		0.5	А	



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST COND	DITIONS	VALUES	UNITS
		3 A	T.I = 25 °C	0.81	v
Maximum forward voltage drop	V _{EM} ⁽¹⁾	6 A	1j=25 0	0.96	
See fig. 1	VFM \''	3 A	T.I = 125 °C	0.63	
		6 A	1j = 125 C	0.74	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	V Detect V	1	mA
See fig. 2	IRM \''	T _J = 125 °C	V _R = Rated V _R	4.9	
Threshold voltage	V _{F(TO)}		$T_J = T_J$ maximum		V
Forward slope resistance	r _t	ij = ij maximum			mΩ
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		92	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0			nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µ			V/µs

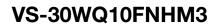
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

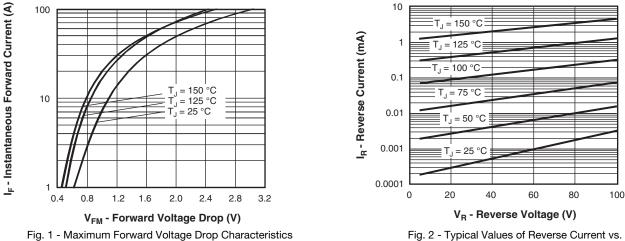
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T_{J} ⁽¹⁾ , T_{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W	
Approximate weight			0.3	g	
			0.01	oz.	
Marking device		Case style D-PAK	30WQ	10FNH	

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



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Reverse Voltage

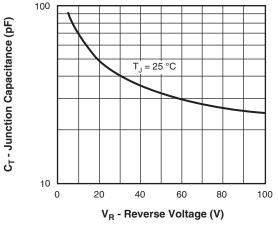


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

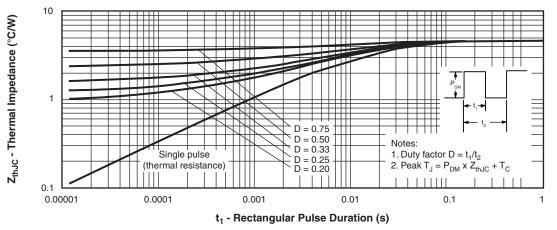


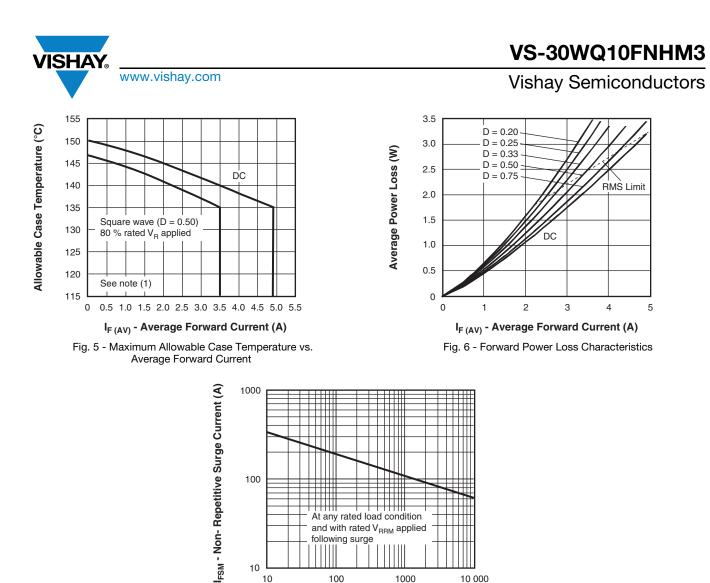
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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At any rated load condition and with rated V_{RRM} applied

tp - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current

 $\left| \right| \left| \right|$

following surge

100

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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Device code	VS-	30	w	Q	10	FN	TRL	н	M3
Device code	V3-	50	••						
		2	3	4	5	6	7	8	9
	1 -	Visl	nay Sen	niconduo	ctors pro	oduct			
	2 .		•	ng (3.5 /					
	3 -	Pac	kage id	entifier:					
		W =	D-PAK						
	4	Sch	ottky "C	" series					
	5 -	Volt	age rati	ng (10 =	= 100 V)				
	6	· FN	= TO-25	52AA (D	-PAK)				
	7	• N	one = T	ube					
		• TI	R = Tap	e and re	el				
		• TF	RL = Ta	pe and r	eel (left	oriente	d)		
		• TF	RR = Ta	pe and	reel (rig	ht orien	ted)		
	8	• H=	AEC-Q	101 qua	alified				
	9.	- Env	vironmer	ntal digit					
		М3	= Halog	en-free,	RoHS-	complia	ant, and	termina	tions le

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-30WQ10FNHM3	75	3000	Antistatic plastic tube				
VS-30WQ10FNTRHM3	2000	2000	13" diameter reel				
VS-30WQ10FNTRRHM3	3000	3000	13" diameter reel				
VS-30WQ10FNTRLHM3	3000	3000	13" diameter reel				

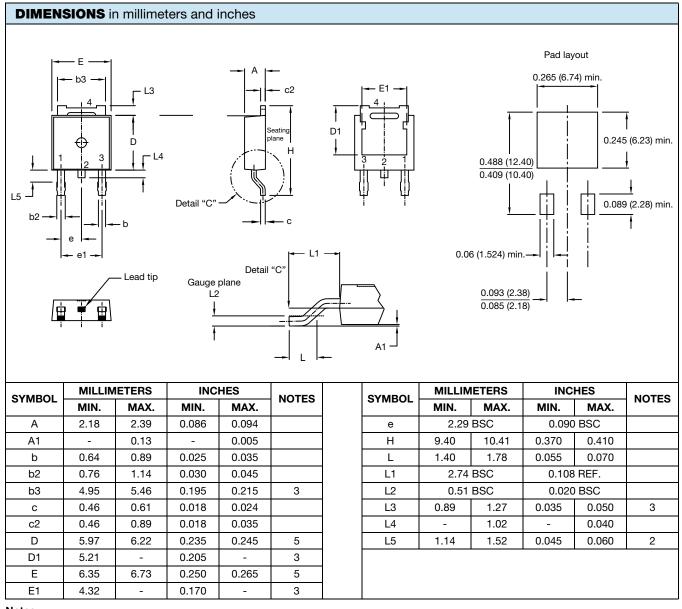
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				

Outline Dimensions



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DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA

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